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捷多邦，专业PCB打样工厂，24小时加急出货

## Photointerrupters(Reflective)

KODENSHI

SG - 107

The SG - 107 reflective sensor combines a GaAs IRED with a high - sensitivity phototransistor in a super - mini package, reducing installation space.

### FEATURES

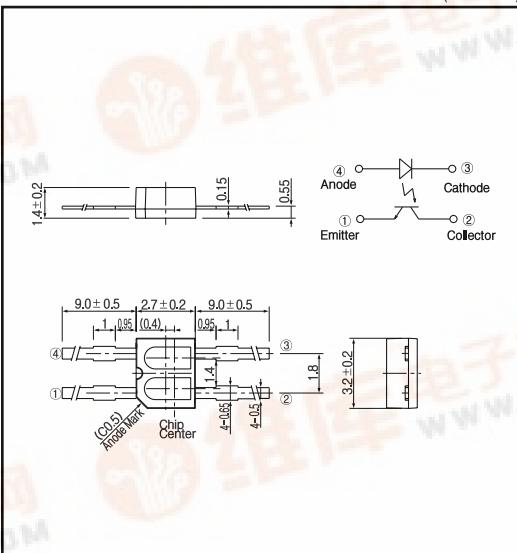
- Compact
- High performance
- High - speed response
- Easy to mount on P.C.B.
- Widely applicable

### APPLICATIONS

- Timing sensors
- Edge sensors
- Micro floppy disk drives
- Level sensors of liquid

### DIMENSIONS

(Unit : mm)



### MAXIMUM RATINGS

(Ta=25 °C)

| Item          | Symbol            | Rating            | Unit    |
|---------------|-------------------|-------------------|---------|
| Input         | P <sub>o</sub>    | 75                | mW      |
|               | V <sub>R</sub>    | 5                 | V       |
|               | I <sub>F</sub>    | 50                | mA      |
|               | I <sub>FP</sub>   | 1                 | A       |
| Output        | P <sub>c</sub>    | 50                | mW      |
|               | I <sub>c</sub>    | 20                | mA      |
|               | V <sub>CEO</sub>  | 30                | V       |
|               | V <sub>ECD</sub>  | 3                 | V       |
|               | Operating temp.   | T <sub>opr.</sub> | -25 +85 |
| Storage temp. | T <sub>stg.</sub> | -30 +100          |         |
|               | T <sub>sol.</sub> | 240               |         |

\*1. t<sub>w</sub> = 100 μsec, period : T=10msec.

\*2. For MAX. 5 seconds at the position of 2mm from the package

### ELECTRO-OPTICAL CHARACTERISTICS

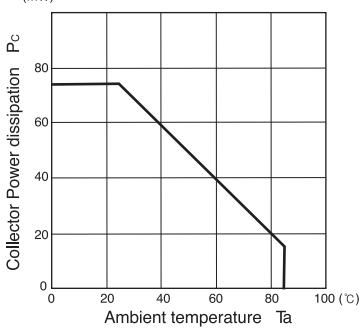
(Ta=25 °C)

| Item             | Symbol           | Conditions                                       | Min. | Typ. | Max. | Unit. |
|------------------|------------------|--|------|------|------|-------|
| Input            | V <sub>F</sub>   | I <sub>F</sub> =10mA                             |      |      | 1.3  | V     |
|                  | I <sub>R</sub>   | V <sub>R</sub> =5V                               |      |      | 10   | μA    |
|                  | p                |  |      | 940  |      | nm    |
| Output           | I <sub>CEO</sub> | V <sub>CE</sub> =10V                             |      |      | 0.2  | μA    |
|                  | I <sub>L</sub>   | V <sub>CE</sub> =5V, I <sub>F</sub> =4mA         | 35   | 5    |      | μA    |
| Switching speeds | I <sub>CED</sub> | V <sub>CE</sub> =5V, I <sub>F</sub> =10mA        |      |      | 0.2  | μA    |
|                  | tr               | V <sub>CC</sub> =2V, I <sub>F</sub> =100μA, R=1k |      | 30   |      | μsec. |
|                  | tf               |  |      | 25   |      | μsec. |

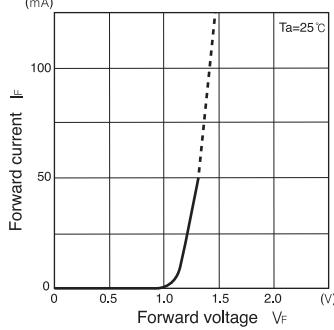
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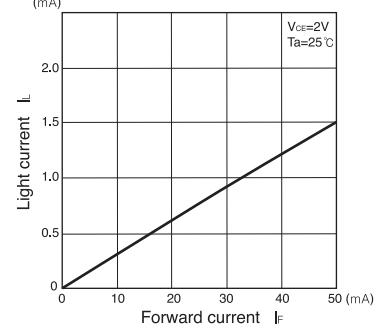
**Collector power dissipation Vs.  
Ambient temperature**



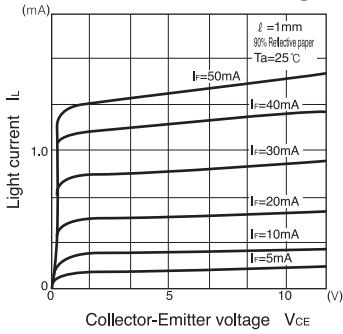
**Forward current Vs.  
Forward voltage**



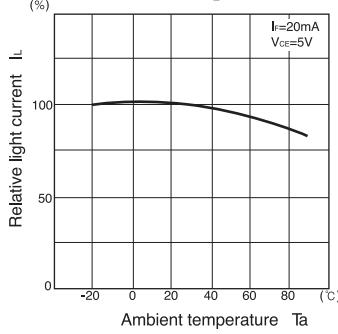
**Light current Vs.  
Forward current**



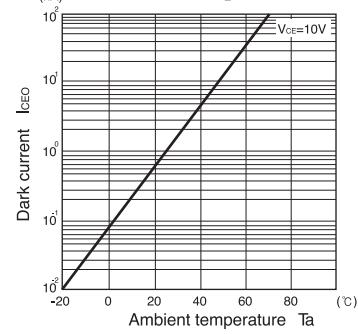
**Light current Vs.  
Collector-Emitter voltage**



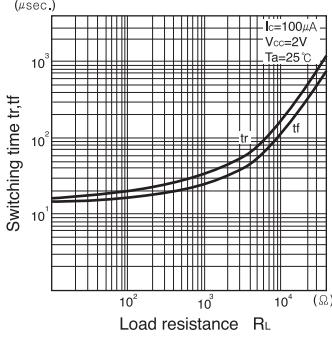
**Relative light current Vs.  
Ambient temperature**



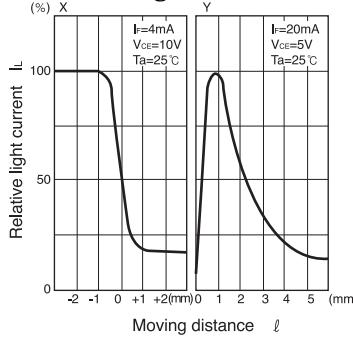
**Dark current Vs.  
Ambient temperature**



**Switching time Vs.  
Load resistance**



**Relative light current Vs.  
Moving distance**



Switching time measurement circuit

